

DSC61XX

Ultra-Small, Ultra-Low Power MEMS Oscillator

Features

- Wide Frequency Range: 2 kHz to 100 MHz
- Ultra-Low Power Consumption: 3 mA/12 μA (Active/Standby)
- Ultra-Small Footprints
 - 1.6 mm × 1.2 mm
 - $2.0 \text{ mm} \times 1.6 \text{ mm}$
 - $2.5 \text{ mm} \times 2.0 \text{ mm}$
 - 3.2 mm × 2.5 mm
- Frequency Select Input Supports Two Pre-Defined Frequencies
- High Stability: ±25 ppm, ±50 ppm
- · Wide Temperature Range
 - Industrial: -40°C to 85°C
 - Ext. Commercial: –20° to 70°C
- · Excellent Shock and Vibration Immunity
 - Qualified to MIL-STD-883
- · High Reliability
 - 20x Better MTF Than Quartz Oscillators
- Supply Range of 1.71V to 3.63V
- Short Sample Lead Time: <2 weeks
- · Lead Free & RoHS Compliant

Applications

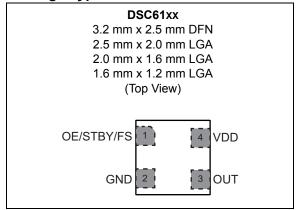
- Low Power/Portable Applications: IoT, Embedded/Smart Devices
- Consumer: Home Healthcare, Fitness Devices, Home Automation
- Automotive: Rear View/Surround View Cameras, Infotainment System
- Industrial: Building/Factory Automation, Surveillance Camera

General Description

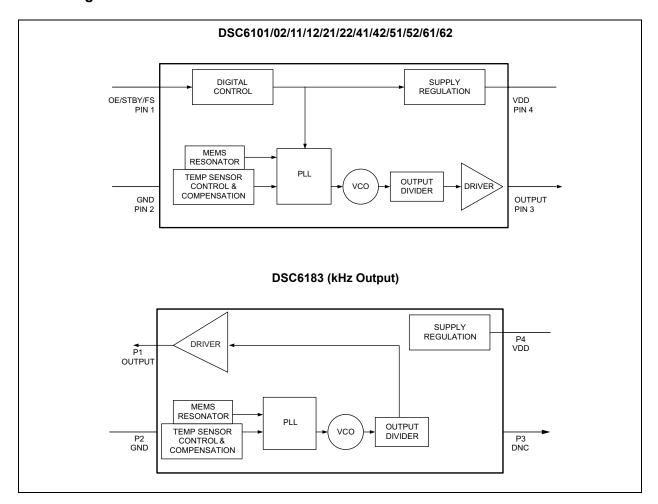
The DSC61xx family of MEMS oscillators combines the industry leading low power consumption and ultra-small packages with exceptional frequency stability and jitter performance over temperature. The single-output DSC61xx MEMS oscillators are excellent choices for use as clock references in small, battery-powered devices such as wearable and Internet of Things (IoT) devices in which small size, low power consumption, and long-term reliability are paramount. They also meet the stringent mechanical durability and reliability requirements within Automotive Electronics Council standard Q100 (AEC-Q100), so they are well suited for under-hood applications as well.

The DSC61xx family is available in ultra-small $1.6~\text{mm} \times 1.2~\text{mm}$ and $2.0~\text{mm} \times 1.6~\text{mm}$ packages. Other package sizes include: $2.5~\text{mm} \times 2.0~\text{mm}$ and $3.2~\text{mm} \times 2.5~\text{mm}$. These packages are "drop-in" replacements for standard 4-pin CMOS quartz crystal oscillators.

Package Types



Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings

Supply Voltage	
Input Voltage (V _{IN})	
ESD Protection	22

ELECTRICAL CHARACTERISTICS

Electrical Characteristics: Unless otherwise indicated, V _{DD} = 1.8V –5% to 3.3V +10%, T _A = –40°C to 85°C.							
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions	
Supply Voltage, Note 1	V_{DD}	1.71		3.63	V		
Power Supply Ramp	t _{PU}	0.1	1	100	ms	Note 8	
Active Supply Current	I _{DD}	_	3.0	_	mA	F_{OUT} = 27 MHz, V_{DD} = 1.8V, No Load	
Standby Supply Current	la-ny.	_	12	_		V _{DD} = 1.8/2.5V	
Note 2	I _{STBY}	_	80	_	μA	V _{DD} = 3.3V	
Frequency Stability Note 3	Δf	_	1	±25 ±50	ppm	All temp ranges	
Aging	۸f	_	1	±5	nnm	1st year @ 25°C	
Aging	Δf	_	1	±1	ppm	Per year after first year	
Startup Time	$t_{\rm SU}$	_	_	1.3	ms	From 90% V _{DD} to valid clock output, T = 25°C	
Input Logic Lovele Note 4	V_{IH}	0.7 x V _{DD}	1	_	V	Input Logic High	
Input Logic Levels Note 4	V_{IL}	_	1	0.3 x V _{DD}	V	Input Logic Low	
Output Disable Time Note 5	t_{DA}	_	_	200+Period	ns	_	
Output Enable Time Note 6	$t_{\sf EN}$		-	1	μs	_	
Enable Pull-up Resistor Note 7	_	_	300	_	kΩ	If configured	
		0.0\				Output Logic High, I = 3 mA, Std. Drive	
	V _{OH}	0.8 x V _{DD}	_	_	V	Output Logic High, I = 6 mA, High Drive	
Output Logic Levels	V		_	0.2 × 1/	V	Output Logic Low, I = -3 mA, Std. Drive	
	V _{OL}	_		0.2 x V _{DD}		Output Logic Low, I = -3 mA, High Drive	

- **Note 1:** Pin 4 V_{DD} should be filtered with 0.1 μ F capacitor.
 - 2: Not including current through pull-up resistor on EN pin (if configured). Higher standby current seen at >3.3V V_{DD}.
 - **3:** Includes frequency variations due to initial tolerance, temp. and power supply voltage.
 - 4: Input waveform must be monotonic with rise/fall time < 10 ms
 - **5:** Output Disable time takes up to one period of the output waveform + 200 ns.
 - 6: For parts configured with OE, not Standby.
 - **7:** Output is enabled if pad is floated or not connected.
 - 8: Time to reach 90% of target V_{DD} . Power ramp rise must be monotonic.

DSC61XX

ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: Unless otherwise indicated, $V_{DD} = 1.8V - 5\%$ to 3.3V +10%, $T_A = -40$ °C to 85°C.								
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions		
Output Transition Time Rise Time/Fall Time	t _{RX} /t _{FX}	_	1	1.5	ns	DSC61x2 High Drive,	V _{DD} = 1.8V	
		_	0.5	1.0	ns	20% to 80% C _L = 15 pF	V _{DD} = 2.5V/3.3V	
	t _{RY} /t _{FY}	_	1.2	2.0	ns	DSC61x1 Std Drive, 20% to 80% C _L = 10 pF	V _{DD} = 1.8V	
		_	1.5	2.2	ns		V _{DD} = 2.5V/3.3V	
Frequency	f ₀	0.002	_	100	MHz	Output on F	in 1 for < 1 MHz	
Output Duty Cycle	SYM	45	_	55	%		_	
Davied litter DMC		_	9.5	11		F _{OUT} =	V _{DD} = 1.8V	
Period Jitter, RMS	J_{PER}	_	7.5	9	ps _{RMS}	27 MHz	$V_{DD} = 2.5 V/3.3 V$	
Cycle-to-Cycle Jitter (peak)		_	50	70	ps	F _{OUT} =	V _{DD} = 1.8V	
	J _{Cy–Cy}	_	35	60		27 MHz	$V_{DD} = 2.5 V/3.3 V$	

- Note 1: Pin 4 V_{DD} should be filtered with 0.1 μF capacitor.
 - 2: Not including current through pull-up resistor on EN pin (if configured). Higher standby current seen at >3.3V V_{DD}.
 - 3: Includes frequency variations due to initial tolerance, temp. and power supply voltage.
 - 4: Input waveform must be monotonic with rise/fall time < 10 ms
 - 5: Output Disable time takes up to one period of the output waveform + 200 ns.
 - **6:** For parts configured with OE, not Standby.
 - **7:** Output is enabled if pad is floated or not connected.
 - 8: Time to reach 90% of target V_{DD} . Power ramp rise must be monotonic.

TEMPERATURE SPECIFICATIONS (Note 1)

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Temperature Ranges						
Junction Operating Temperature	TJ	_	_	+150	°C	_
Ambient Operating Temperature	T _A	-4 0	_	+85	°C	Industrial
Ambient Operating Temperature	T _A	-20	_	+70	°C	Extended Commercial
Storage Ambient Temperature Range	T _A	-55	_	+150	°C	_
Soldering Temperature	T _S	_	+260	_	°C	40 sec. max.

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +150°C rating. Sustained junction temperatures above +150°C can impact the device reliability.

2.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 2-1 and Table 2-2.

TABLE 2-1: DSC6101/02/11/12/21/22/41/42/51/52/61/62 PIN FUNCTION TABLE (OUTPUT FREQUENCY ≥1 MHZ)

Pin Number	Pin Name	Pin Type	Description
	OE		Output Enable: H = Specified Frequency Output, Note 1 L = Output is high impedance
1	STBY	I	Standby: H = Specified Frequency Output, Note 1 L = Output is high impedance. Device is in low power mode, supply current is at I _{STBY}
	FS		Frequency Select: H = Output Frequency 1, Note 2 L = Output Frequency 2
2	GND	Power	Power supply ground
3	Output	0	Oscillator clock output
4	VDD	Power	Power supply

- **Note 1:** DSC610x/1x/2x has 300 k Ω internal pull-up resistor on pin1. DSC614x/5x/6x has no internal pull-up resistor on pin1 and needs external pull-up or being driven by other chip.
 - 2: Two pre-programmed frequencies can be configured at http://clockworks.microchip.com/timing/
 - 3: Bypass with 0.1 μ F capacitor placed as close to V_{DD} pin as possible.

TABLE 2-2: DSC6183 PIN FUNCTION TABLE (OUTPUT FREQUENCY < 1 MHZ)

Pin Number	Pin Name	Pin Type	Description
1	Output	0	Kilohertz Oscillator clock output
2	GND	Power	Power supply ground
3	DNC	DNC	Do Not Connect
4	VDD	Power	Power supply, Note 1

Note 1: Bypass with 0.1 μF capacitor placed as close to V_{DD} pin as possible.

2.1 Output Buffer Options

DSC61xx family is available in multiple output driver configurations.

The standard-drive (61x1) and high-drive (61x2) deliver respective output currents of greater than 3 mA and 6 mA at 20%/80% of the supply voltage. For heavy loads of 15 pF or higher, the high-drive option is recommended.

3.0 DIAGRAMS

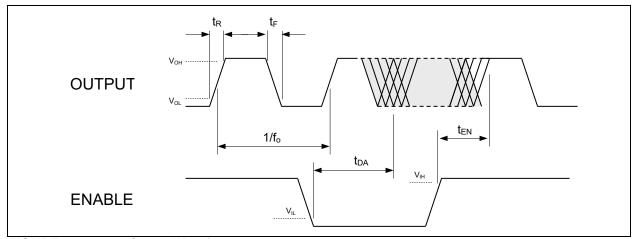


FIGURE 3-1: Output Waveform.

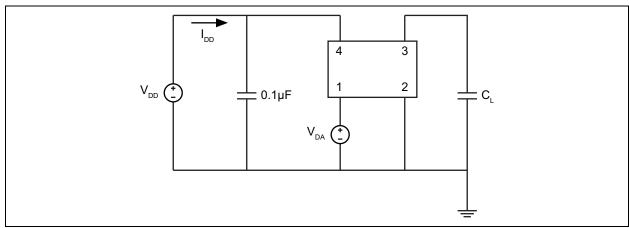


FIGURE 3-2: Test Circuit.

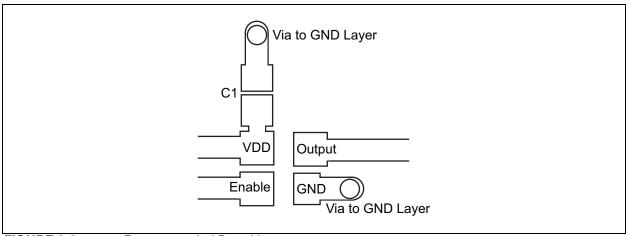


FIGURE 3-3: Recommended Board Layout.

4.0 SOLDER REFLOW PROFILE

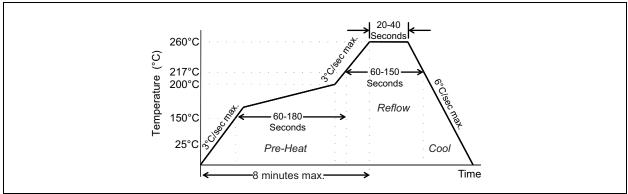
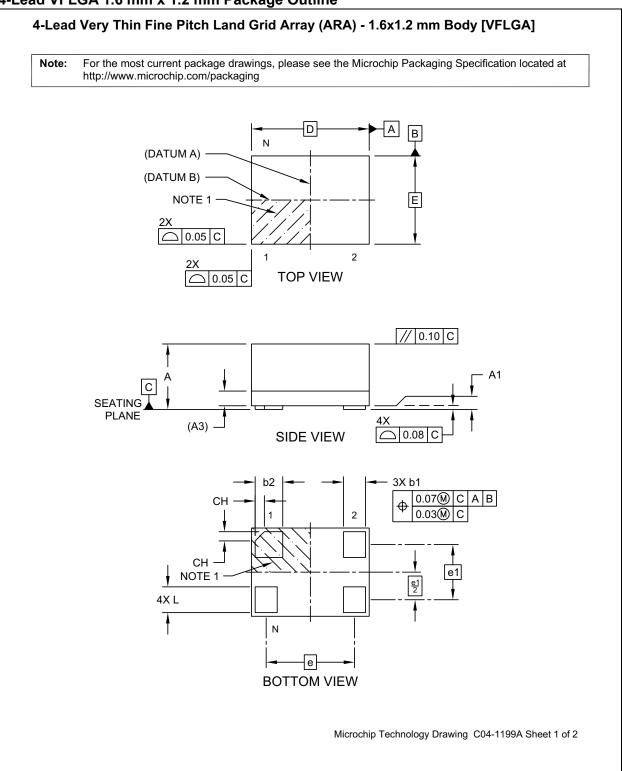


FIGURE 4-1: Solder Reflow Profile.

MSL 1 @ 260°C refer to	JSTD-020C
Ramp-Up Rate (200°C to Peak Temp)	3°C/sec. max.
Preheat Time 150°C to 200°C	60 to 180 sec.
Time maintained above 217°C	60 to 150 sec.
Peak Temperature	255°C to 260°C
Time within 5°C of actual Peak	20 to 40 sec.
Ramp-Down Rate	6°C/sec. max.
Time 25°C to Peak Temperature	8 minutes max.

5.0 PACKAGING INFORMATION

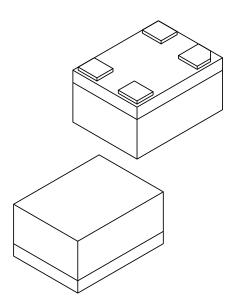
4-Lead VFLGA 1.6 mm x 1.2 mm Package Outline



4-Lead VFLGA 1.6 mm x 1.2 mm Package Outline

4-Lead Very Thin Fine Pitch Land Grid Array (ARA) - 1.6x1.2 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	MIN	NOM	MAX	
Number of Terminals	N		4	
Terminal Pitch	е		1.20 BSC	
Terminal Pitch	e1	0.75 BSC		
Overall Height	Α	0.79	0.84	0.89
Standoff	A1	0.00	0.02	0.05
Substrate Thickness (with Terminals)	A3		0.20 REF	
Overall Length	D		1.60 BSC	
Overall Width	Е		1.20 BSC	
Terminal Width	b1	0.25	0.30	0.35
Terminal Width	b2	0.325	0.375	0.425
Terminal Length	Ĺ	0.30	0.35	0.40
Terminal 1 Index Chamfer	CH	-	0.125	-

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

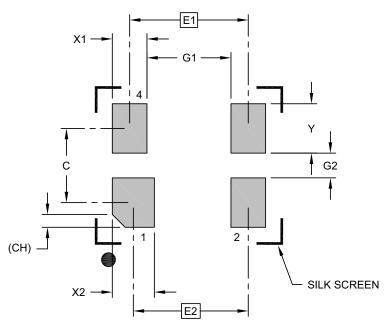
REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1199A Sheet 2 of 2

4-Lead VFLGA 1.6 mm x 1.2 mm Recommended Land Pattern

4-Lead Very Thin Fine Pitch Land Grid Array (ARA) - 1.6x1.2 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX
Contact Pitch	E1		1.20 BSC	
Contact Pitch	E2		1.16 BSC	
Contact Spacing	С		0.75	
Contact Width (X3)	X1			0.35
Contact Width	X2			0.43
Contact Pad Length (X6)	Υ			0.50
Space Between Contacts (X4)	G1	0.85		
Space Between Contacts (X3)	G2	0.25		
Contact 1 Index Chamfer	СН	0.13 X 45° REF		

Notes:

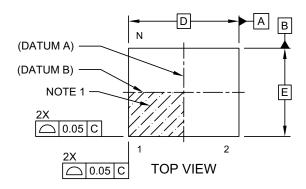
Dimensioning and tolerancing per ASME Y14.5M
 BSC: Basic Dimension. Theoretically exact value shown without tolerances.

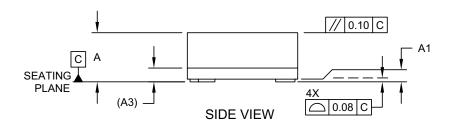
Microchip Technology Drawing C04-3199A

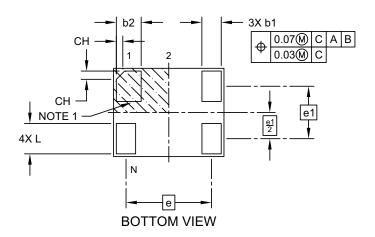
4-Lead VFLGA 2.0 mm x 1.6 mm Package Outline

4-Lead Very Thin Fine Pitch Land Grid Array (ASA) - 2.0x1.6 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging





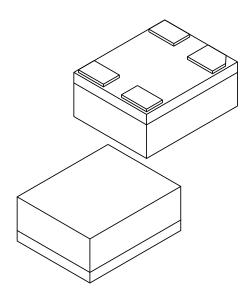


Microchip Technology Drawing C04-1200A Sheet 1 of 2

4-Lead VFLGA 2.0 mm x 1.6 mm Package Outline

4-Lead Very Thin Fine Pitch Land Grid Array (ASA) - 2.0x1.6 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	Dimension Limits		NOM	MAX
Number of Terminals	N		6	
Terminal Pitch	е		1.55 BSC	
Terminal Pitch	e1	0.95 BSC		
Overall Height	Α	0.79	0.84	0.89
Standoff	A1	0.00	0.02	0.05
Substrate Thickness (with Terminals)	A3	0.20 REF		
Overall Length	D		2.00 BSC	
Overall Width	Е		1.60 BSC	
Terminal Width	b1	0.30	0.35	0.40
Terminal Width	b2	0.40	0.45	0.50
Terminal Length	Ĺ	0.50	0.55	0.60
Terminal 1 Index Chamfer	СН	-	0.15	-

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

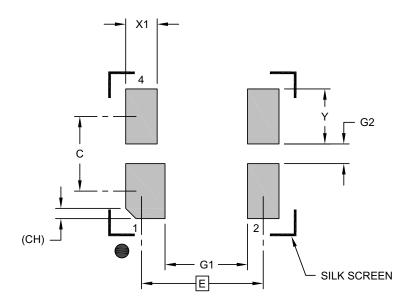
REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1200A Sheet 2 of 2

4-Lead VFLGA 2.0 mm x 1.6 mm Package Outline

4-Lead Very Thin Fine Pitch Land Grid Array (ASA) - 2.0x1.6 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS				
Dimension	MIN	NOM	MAX		
Contact Pitch	Е		1.55 BSC		
Contact Spacing	O		0.95		
Contact Width (X4)	X1			0.50	
Contact Width (X2)	X2			0.40	
Contact Pad Length (X6)	Υ			0.70	
Space Between Contacts (X4)	G1	1.05			
Space Between Contacts (X3)	G2	0.25			
Contact 1 Index Chamfer	CH	0.13 X 45° REF			

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

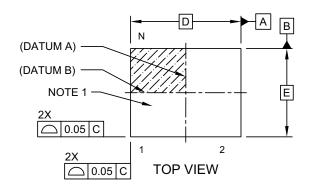
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

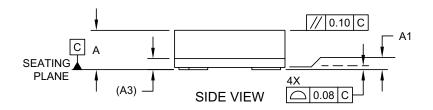
Microchip Technology Drawing C04-3200A

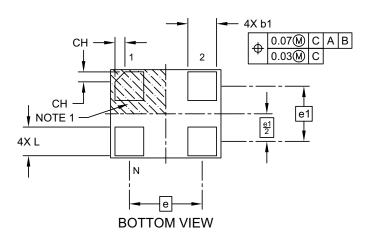
4-Lead VLGA 2.5 mm x 2.0 mm Package Outline

4-Lead Very Thin Land Grid Array (AUA) - 2.5x2.0 mm Body [VLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging





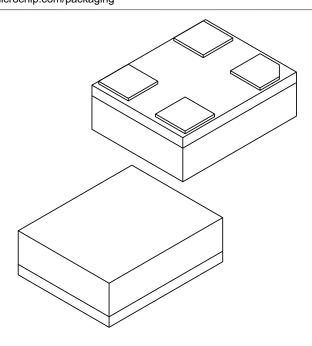


Microchip Technology Drawing C04-1202A Sheet 1 of 2

4-Lead VLGA 2.5 mm x 2.0 mm Package Outline

4-Lead Very Thin Land Grid Array (AUA) - 2.5x2.0 mm Body [VLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS				
Dimension	Dimension Limits			MAX	
Number of Terminals	N		4		
Terminal Pitch	е		1.65 BSC		
Terminal Pitch	e1	1.25 BSC			
Overall Height	Α	0.79	0.84	0.89	
Standoff	A1	0.00	0.02	0.05	
Substrate Thickness (with Terminals)	A3		0.20 REF		
Overall Length	D		2.50 BSC		
Overall Width	Е	2.00 BSC			
Terminal Width	b1	0.60	0.65	0.70	
Terminal Length	L	0.60	0.65	0.70	
Terminal 1 Index Chamfer	СН	-	0.225	-	

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M $\,$

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

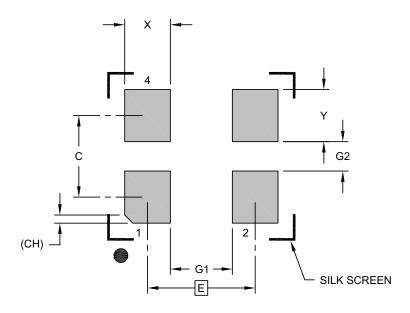
REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1202A Sheet 2 of 2

4-Lead VLGA 2.5 mm x 2.0 mm Recommended Land Pattern

4-Lead Very Thin Land Grid Array (AUA) - 2.5x2.0 mm Body [VLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	Е	1.65 BSC		
Contact Spacing	С		1.25	
Contact Width (X4)	Х			0.70
Contact Pad Length (X6)	Υ			0.80
Space Between Contacts (X4)	G1	0.95		
Space Between Contacts (X3)	G2	0.45		
Contact 1 Index Chamfer	CH	0.13 X 45° REF		

Notes:

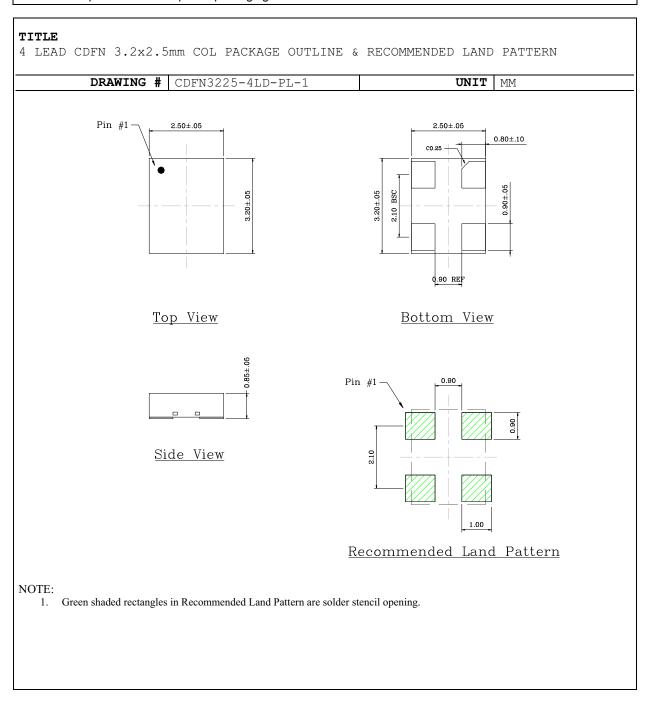
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-3202A

4-Lead CDFN 3.2 mm x 2.5 mm Package Outline and Recommended Land Pattern

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



APPENDIX A: REVISION HISTORY

Revision A (September 2016)

 Initial release of DSC61xx Microchip data sheet DS20005624A.

Revision B (September 2017)

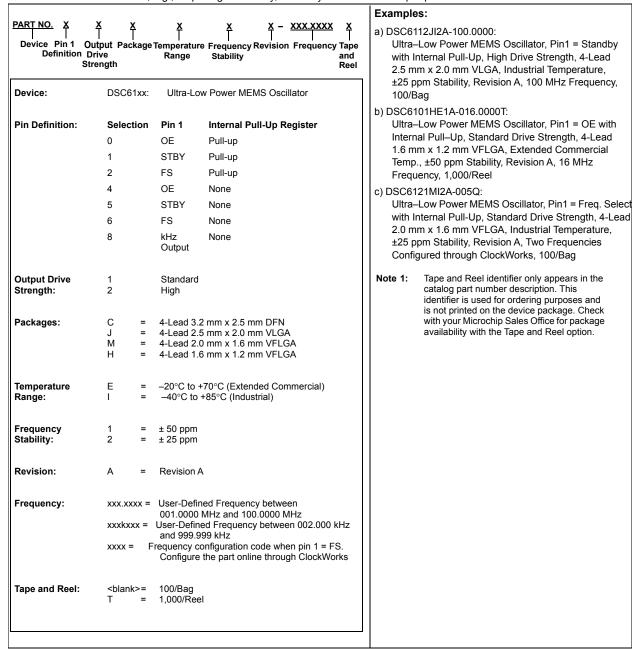
- Added Power Supply Ramp value in Electrical Characteristics table.
- Redrew diagrams for clarity. No technical content affected.



NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.



Note 1: Please visit Microchip ClockWorks[®] Configurator Website to configure the part number for customized frequency. http://clockworks.microchip.com/timing/.



NOTES:

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